

PATENT ASSIGNMENT

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SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT
CONVEYING PARTY DATA	
Name	Execution Date
Lumei Optoelectronics Corporation	05/18/2011
RECEIVING PARTY DATA	
Name:	Dalian Meiming Epitaxy Technology Co., Ltd.
Street Address:	Light Industrial Park, Economic and Technological Development Zone
City:	Dalian
State/Country:	CHINA
Postal Code:	116600
PROPERTY NUMBERS Total: 1	
Property Type	Number
Patent Number:	6643304
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ATTORNEY DOCKET NUMBER:	71442.0008
NAME OF SUBMITTER:	Jean C. Edwards
Total Attachments: 3 source=Executed Assignment#page1.tif source=Executed Assignment#page2.tif source=Executed Assignment#page3.tif	

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ASSIGNMENT

WHEREAS, Lumei Optoelectronics Corporation, having an address of 9650 Telstar Avenue, El Monte, California 91731, ("Assignor"), owns and holds all right, title and interest in, to and under the inventions as set forth in the attached Schedule A; and

WHEREAS, Dalian Meiming Epitaxy Technology Co., Ltd., having an address of Light Industrial Park, Economic and Technological Development Zone, Dalian, China, 116600, ("Assignee"), is desirous of acquiring the entire right, title and interest in and to said inventions, and in and to any and all Letters Patent of the United States and foreign countries which may be obtained therefore;

NOW, THEREFORE, for good and valuable consideration, the receipt for and sufficiency of which is hereby acknowledged, Assignor does hereby sell, assign, transfer and set over unto Assignee, its legal representatives, successors and assigns, the entire right, title and interest in and to said inventions, including the right to claim priority under 35 U.S.C. §119 and the right to sue for past infringement, as set forth in the applications and patents referenced on Schedule A, including any continuations, continuations-in-part, divisions, reissues, re-examinations or extensions thereof, and in and to any and all patents of the United States and foreign countries which may have or may be issued for said inventions;

UPON SAID CONSIDERATION, Assignor hereby agrees with the said Assignee that Assignor will not execute any writing or do any act whatsoever conflicting with these presents, and that Assignor will, at any time upon request, without further or additional consideration but at the expense of said Assignee, execute such additional assignments and other writings and do such additional acts as said Assignee may deem necessary or desirable to perfect the Assignee's enjoyment of this grant, and render all necessary assistance in making application for and obtaining original, divisional, continuations, continuations-in-part, reexamined, reissued, or extended Letters Patent of the United States or of any and all foreign countries on said inventions, and in enforcing any rights or chooses in action accruing as a result of such applications or patents, by giving testimony in any proceedings or transactions involving such applications or patents, and by executing preliminary statements and other affidavits, it being understood that the foregoing covenant and agreement shall bind, and inure to the benefit of the assigns and legal representatives of Assignor and Assignee;

WHEREAS, if the Assignee is unable for any reason whatsoever to secure the Assignor's signature to any document it is entitled to under this Assignment, Assignor hereby irrevocably designates and appoints the Assignor and its duly authorized officers and agents, as Assignee's agents and attorneys-in-fact with full power of substitution to act for and on its behalf and instead of Assignor, to execute and file any such papers and to do all other lawfully permitted acts to further the purposes of the foregoing with the same legal force and effect as if executed by Assignor;

WHEREAS, this Assignment is assignable or transferable by Assignee without notice or consent of the Assignor;

The undersigned hereby grants the firm of EDWARDS NEILS PLLC the power to insert on this Assignment any further identification, including the application numbers and filing dates, which may be necessary or desirable in order to comply with the rules of the United States Patent and Trademark Office for recordation of this document.

WHEREAS, if any provision of this Assignment shall be adjudged by any court of competent jurisdiction to be unenforceable or invalid, that provision shall be limited or eliminated to the minimum extent necessary so that this Assignment shall otherwise remain in full force and effect and enforceable;

Customer No.: 13155

AND, Assignor authorizes and requests the Commissioner of Patents and Trademarks and any official of any foreign country whose duty it is to issue patents for said inventions to said Assignee, its legal representatives, successors or assigns, as the sole owner of the entire right, title and interest in and to said patents and the inventions covered thereby.

Date: May 18, 2011

Zhiguo Xiao
Xiao Zhiguo
Chairman and CEO
Lumei Optoelectronics Corporation

(NOTE: Legalization is not required for recording, but is *prima facie* evidence of execution under 35 U.S.C. 261).

Schedule A to Assignment

Attorney Reference No.	Country	Application No.	Filing Date	Patent No.	Issue Date	Title
71442.0008	USA	09/626,444	07/26/2000	6,643,304	11/04/2003	Transparent Substrate Light Emitting Diode
71442.0004	USA	09/626,442	07/26/2000	6,495,867	12/17/2002	InGaN/AlGaIn/GaN Multilayer Buffer For Growth Of GaN On Sapphire
71442.0015	USA	10/147,078	05/17/2002	6,919,585	07/19/2005	Light Emitting Diode With Silicon Carbide Substrate
71442.0018	USA	10/191,886	07/08/2002	6,630,695	10/07/2003	InGaN/AlGaIn/GaN Multilayer Buffer For Growth Of GaN On Sapphire
71442.0019	USA	10/197,614	07/15/2002	6,642,549	11/04/2003	Method Of Forming A Window For A Gallium Nitride Light Emitting Diode
71442.0049	USA	11/044,714	01/28/2005	7,193,245	03/20/2007	High Power, High Luminous Flux Light Emitting Diode And Method Of Making Same